## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re	Patent Application of	)	
AKIH	ISA SHIMOMURA et al.	)	ATTN: New Applications
Base	d On: JP 2002-191493	)	
Filed:	June 28, 2002	)	
For:	METHOD OF MANUFACTO	JRING)	
	A SEMICONDUCTOR DEV	ICE )	

## **INFORMATION DISCLOSURE STATEMENT**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, Applicant submits herewith a Form PTO-1449 listing references known to Applicant and requests that these references be made of record in the above identified application. Copies of the references listed are submitted herewith in accordance with 37 C.F.R. 1.98(a).

- U.S. Publication No. 2002/0048864 and U.S. Publication No. 2002/0004292 are in the family of JP 2001-144027.
  - U.S. Publication No. 2002/0014625 is in the family of JP 2002-124685.
  - U.S. Publication No. 2002/0006705 is in the family of JP 2002-083805.
  - U.S. Publication No. 2002/0098628 is in the family of JP 2002-324808.

The Commissioner is hereby authorized to charge fees under 37 C.F.R. §§1.16, 1.17, 1.20(a), 1.20(b), 1.20(c), and 1.20(d) (except the Issue Fee) which may be required now or hereafter, or credit any overpayment to Deposit Account No. 50-2280. A duplicate copy of this sheet is attached.

Respectfully submitted,

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Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number. Substitute for form 1449A/PTO Complete if Known Based On INFORMATION DISCLOSURE Filing Date June 27, 2003 STATEMENT BY APPLICANT Akihisa SHIMOMURA et al. First Named Inventor (use as many sheets as necessary) Group Art Unit Examiner Name Sheet 2 of Attorney Docket Number 0756-7171

				U.S. PATENT DOCUMENT	rs		
Examiner Initials	Cite No.1	U.S. Patent Docu	ment	Name of Patentee or Applicant of Cited	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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				FOREIGN PATENT DOC	UMENTS			
Examiner Initials	Cite No.1	1	Foreign Patent Document	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		Office <sup>3</sup>	Kind Code <sup>5</sup> Number <sup>4</sup> (if known)				T <sup>6</sup>	
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			OTHER PRIOR	R ART – NON PATENT LITE	RATURE DOCUMENTS			
Examiner Initials*	Cite Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published.							
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Examiner	Date	
Signature	Considered	

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

PTO/SB/08A (08-00)
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)					Based On						
					Filing Date	Filing Date		June	27, 2003		
					First Named Inventor				isa SHIMOMURA	et al.	
					Group Art Unit						
						Examiner Name					
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Initials*	No.1		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published.							T <sup>2</sup>	
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